Ç	P. Code: 20HS0849	R20	
F	leg. No:		
	SIDDHARTH INSTITUTE OF ENGINEERING & TECHNOLOGY:: PI	UTTIND	
	(AUTONOMOUS)	JIIUK	
	B.Tech I Year II Semester Regular Examinations November-20	21	
	APPLIED PHYSICS		
	(Common to EEE & ECE)		
	Fime: 3 hours	Max.	Marks: 60
	(Answer all Five Units $5 \times 12 = 60$ Marks)		
	UNIT-I		
1	a State and explain principle of superposition.	L1	6M
	b Summarizing the importance conditions to get interference.	L2	6M
	OR		
2	a What is Diffraction grating and explain.	L4	8M
	b Find the highest order that can be seen with a grating having 15000 lines/inch The wavelength of the light used is 600 nm.	nes. L4	4M
	UNIT-II		
3		L1	6M
5	a Write brief note on Fermi Dirac distribution.b What is the effect of temperature on Fermi Dirac distribution function?	LI	6M
	OR	A. J. A.	VIVE
4	Explain the propagation of electromagnetic wave in non-conducting media.	L4	12M
	UNIT-III		
5	a Describe the construction and working principle of Nd:YAG Laser with the h	elp L3	9M
	of a neat diagram.		
	b Calculate the wavelength of emitted radiation from GaAs which has a band gap	oof L4	3M
	1.44eV.		
	OR CONTRACT OF CONTRACT.	1	1015
6	Explain the classifications of optical fibers based on refractive index profile	and L4	12M
	mode of propagation.		
7	a What is Fermi level? Prove that the Fermi level is lies exactly in betw	een L4	8M
'	conduction band and valance band of intrinsic semiconductor.		OIVI
	b Draw the energy band structure of intrinsic semiconductor.	L3	4M
	OR		
8	a Explain the formation of p-n junction.	L4	4M
	b Describe the construction and working mechanism of Photodiode.	L3	8M
	UNIT-V		
9	a Explain the Type-I and Type-II superconductors.	L4	7M
	b What is Meissner effect?	L1	5M
10	OR^{-1}	т 4	ATLA
10	a What are the techniques available for synthesizing nanomaterials?b Explain ball milling technique for synthesis of nanomaterial.	L1 L4	4M 8M
	o explain oan mining commute for synthesis of nationaterial.	L_/ *	O148

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